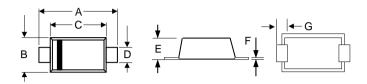


RB521S-30

Silicon Epitaxial Planar Schottky Barrier Diode

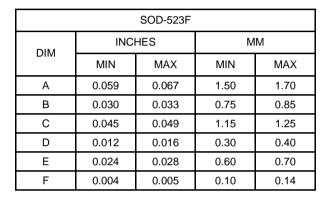
Features

- * Extremely small surface mounting type
- * Marking Code: "C"
- * For low current rectification and high speed switching applications











Maximum Ratings (T_A=25 °C unless otherwise noted)

Parameter	Symbol	Value	Unit
Reverse Voltage	VR	30	V
Mean Rectifying Current	lo	200	mA
Peak Forward Surge Current (60Hz for Cyc.)	Iғsм	1	А
Junction Temperature	Tj	125	$^{\circ}$ C
Storage Temperature Range	T _{stg}	- 40 to + 125	$^{\circ}\!$

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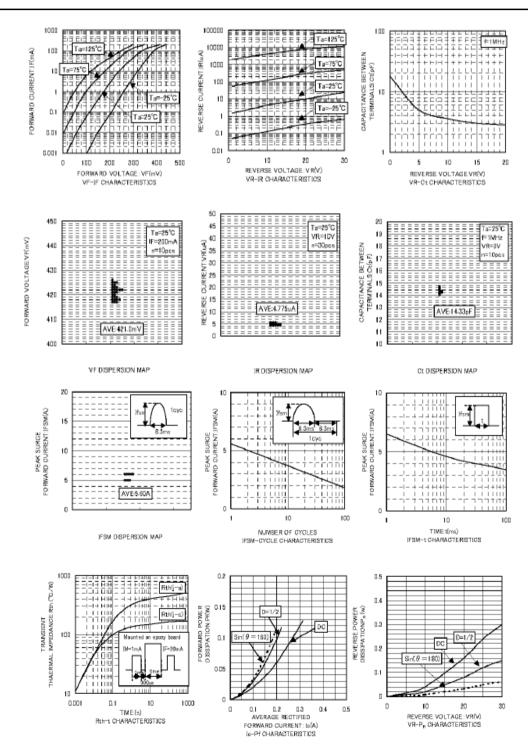
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Silicon Epitaxial Planar Schottky Barrier Diode

Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Max.	Unit
Forward Voltage at I _F = 200 mA	VF	0.5	V
Reverse Current at V _R = 10 V	lR	30	μΑ

Ratings and Characteristic Curves



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RB521S-30

Silicon Epitaxial Planar Schottky Barrier Diode

Ordering Information

Part No.	Package	Packing Code	Packing
RB521S-30	SOD-523F	R30	3000pcs/Reel

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